SGS-THOMSON MICROELECTRONICS

M24C64

SERIAL EXTENDED ADDRESSING COMPATIBLE WITH I²C BUS 64K (8K x 8) EEPROM

- COMPATIBLE with I²C EXTENDED ADDRESSING
- TWO WIRE SERIAL INTERFACE, SUPPORTS 400kHz PROTOCOL
- 100,000 ERASE/WRITE CYCLES, OVER the FULL SUPPLY VOLTAGE RANGE
- 40 YEARS DATA RETENTION
- SINGLE SUPPLY VOLTAGE
  - 4.5V to 5.5V for M24C64 version
  - 1.8V to 5.5V for M24C64-R version
- WRITE CONTROL FEATURE
- BYTE and PAGE WRITE (up to 32 BYTES)
- BYTE, RANDOM and SEQUENTIAL READ MODES
- SELF TIMED PROGRAMING CYCLE
- AUTOMATIC ADDRESS INCREMENTING
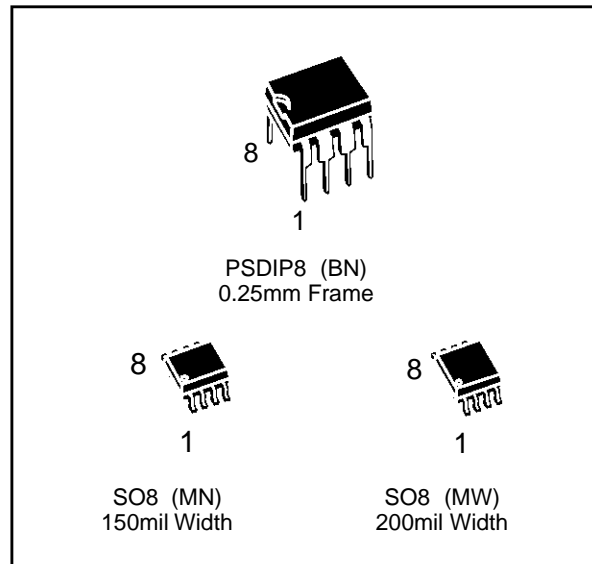- ENHANCED ESD/LATCH UP PERFORMANCES

PSDIP8 (BN)
0.25mm Frame

SO8 (MN)
150mil Width

SO8 (MW)
200mil Width

DESCRIPTION

The M24C64 is a 64K bit electrically erasable pro-grammable memory (EEPROM), organized as 8 blocks of 1024 x 8 bits. The M24C64-R operates with a power supply value as low as 1.8V. Both Plastic Dual-in-Line and Plastic Small Outline pack-ages are available.

Figure 1. Logic Diagram

Table 1. Signal Names

E0 - E2	Chip Enable Inputs
SDA	Serial Data Address Input/Output
SCL	Serial Clock
$\overline{WC}$	Write Control
V_{CC}	Supply Voltage
V_{SS}	Ground
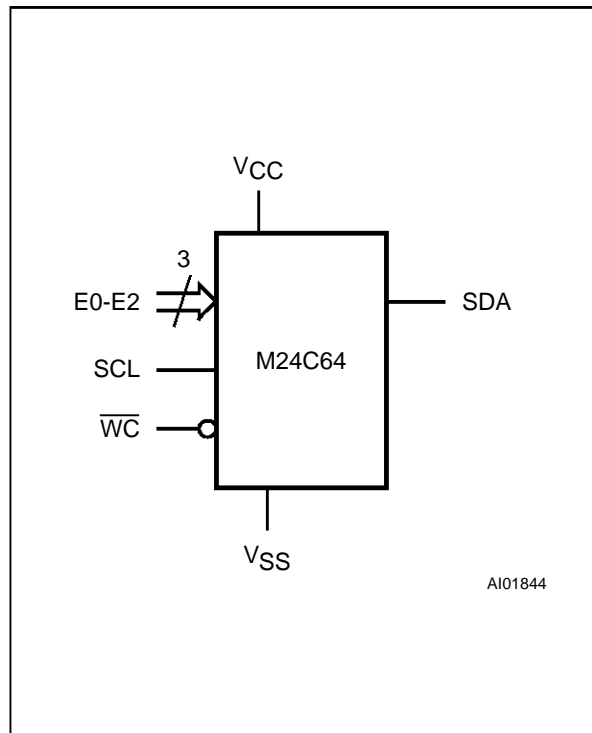
Figure 2A. DIP Pin Connections

M24C64

```
       ┌──┬──┬──┐
E0 ▯   1 │  ◡  │ 8 ▯ V_CC
E1 ▯   2 │     │ 7 ▯ WC
E2 ▯   3 │     │ 6 ▯ SCL
V_SS ▯ 4 │     │ 5 ▯ SDA
       └─────────┘
           AI01845
```
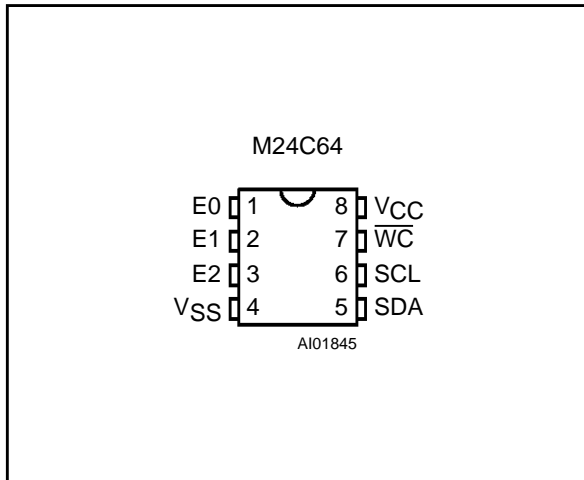
Figure 2B. SO Pin Connections

M24C64

```
       ┌──┬──┬──┐
E0 ▭   1 │  ①  │ 8 ▭ V_CC
E1 ▭   2 │     │ 7 ▭ WC
E2 ▭   3 │     │ 6 ▭ SCL
V_SS ▭ 4 │     │ 5 ▭ SDA
       └─────────┘
           AI01846
```
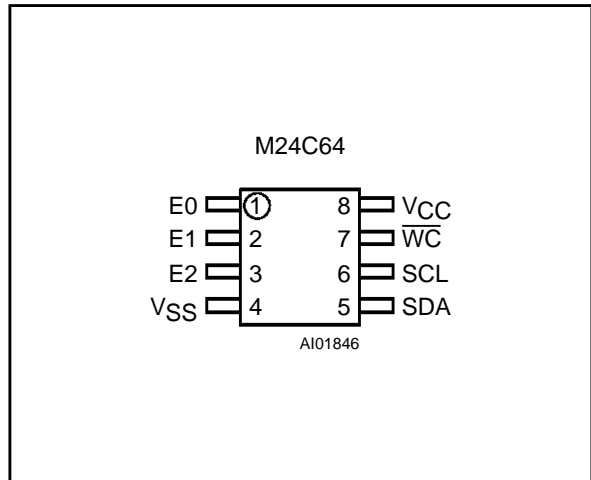
Table 2. Absolute Maximum Ratings [1]

Symbol	Parameter		Value	Unit
T_A	Ambient Operating Temperature		−40 to 125	°C
T_{STG}	Storage Temperature		−65 to 150	°C
T_{LEAD}	Lead Temperature, Soldering (SO8) (PSDIP8)	40 sec 10 sec	215 260	°C
V_{IO}	Input or Output Voltages		−0.6 to 6.5	V
V_{CC}	Supply Voltage		−0.3 to 6.5	V
V_{ESD}	Electrostatic Discharge Voltage (Human Body model) [2]		4000	V
	Electrostatic Discharge Voltage (Machine model) [3]		500	V

Notes: 1. Except for the rating "Operating Temperature Range", stresses above those listed in the Table "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the SGS-THOMSON SURE Program and other relevant quality documents.
2. 100pF through 1500Ω; MIL-STD-883C, 3015.7
3. 200pF through 0Ω; EIAJ IC-121 (condition C)

DESCRIPTION (cont'd)

Each memory is compatible with the I^2C extended addressing standard, two wire serial interface which uses a bi-directional data bus and serial clock. The M24C64 carries a built-in 4 bit, unique device identification code (1010) corresponding to the I^2C bus definition. The M24C64 behaves as slave devices in the I^2C protocol with all memory operations synchronized by the serial clock. Read and write operations are initiated by a START condition generated by the bus master. The START condition is followed by a stream of 4 bits (identification code 1010), 3 bit Chip Enable input to form a 7 bit Device Select, plus one read/write bit and terminated by an acknowledge bit.

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Table 3. Device Select Code

	Device Code				Chip Enable			R$\overline{\text{W}}$
Bit	b7	b6	b5	b4	b3	b2	b1	b0
Device Select	1	0	1	0	E2	E1	E0	R$\overline{\text{W}}$

Note: The MSB b7 is sent first.

Table 4. Operating Modes

Mode	R$\overline{\text{W}}$ bit	Bytes	Initial Sequence
Current Address Read	'1'	1	START, Device Select, R$\overline{\text{W}}$ = '1'
Random Address Read	'0'	1	START, Device Select, R$\overline{\text{W}}$ = '0', Address,
	'1'		reSTART, Device Select, R$\overline{\text{W}}$ = '1'
Sequential Read	'1'	1 to 8192	As CURRENT or RANDOM Mode
Byte Write	'0'	1	START, Device Select, R$\overline{\text{W}}$ = '0'
Page Write	'0'	32	START, Device Select, R$\overline{\text{W}}$ = '0'

When writing data to the memory it responds to the 8 bits received by asserting an acknowledge bit during the 9th bit time. When data is read by the bus master, it acknowledges the receipt of the data bytes in the same way.

Data transfers are terminated with a STOP condition. In this way, up to 8 M24C64 may be connected to the same I^{2}C bus and selected individually, allowing a total addressing field of 512 Kbit.

Power On Reset: V$_{CC}$ lock out write protect. In order to prevent data corruption and inadvertent write operations during power up, a Power On Reset (POR) circuit is implemented. Untill the V$_{CC}$ voltage has reached the POR threshold value, the internal reset is active: all operations are disabled and the device will not respond to any command. In the same way, when V$_{CC}$ drops down from the operating voltage to below the POR threshold value, all operations are disabled and the device will not respond to any command. A stable V$_{CC}$ must be applied before applying any logic signal.

SIGNALS DESCRIPTION

Serial Clock (SCL). The SCL input pin is used to synchronize all data in and out of the memory. A resistor can be connected from the SCL line to V$_{CC}$ to act as a pull up (see Figure 3)

Serial Data (SDA). The SDA pin is bi-directional and is used to transfer data in or out of the memory. It is an open drain output that may be wire-OR'ed with other open drain or open collector signals on the bus. A resistor must be connected from the SDA bus line to V$_{CC}$ to act as pull up (see Figure 3).

Chip Enable (E0 - E2). These chip enable inputs are used to set the 3 least significant bits of the 7 bit device select code. They may be driven dynamically or tied to V$_{CC}$ or V$_{SS}$ to establish the device select code. Note that the V$_{IL}$ and V$_{IH}$ levels for the inputs are CMOS, not TTL compatible.

Write Control ($\overline{\text{WC}}$). The Write Control feature $\overline{\text{WC}}$ is useful to protect the contents of the memory from any erroneous erase/write cycle. The Write Control signal is used to enable ($\overline{\text{WC}}$ at V$_{IH}$) or disable ($\overline{\text{WC}}$ at V$_{IL}$) the internal write protection. When pin $\overline{\text{WC}}$ is unconnected, the $\overline{\text{WC}}$ input is internally read as V$_{IL}$ (see Table 5).

When $\overline{\text{WC}}$ = '1', Device Select and Address bytes are acknowledged; Data bytes are not acknowledged.

Refer to the AN404 Application Note for more detailed information about Write Control feature.

Figure 3. Maximum R_L Value versus Bus Capacitance (C_{BUS}) for an I^2C Bus, f_C = 400kHz
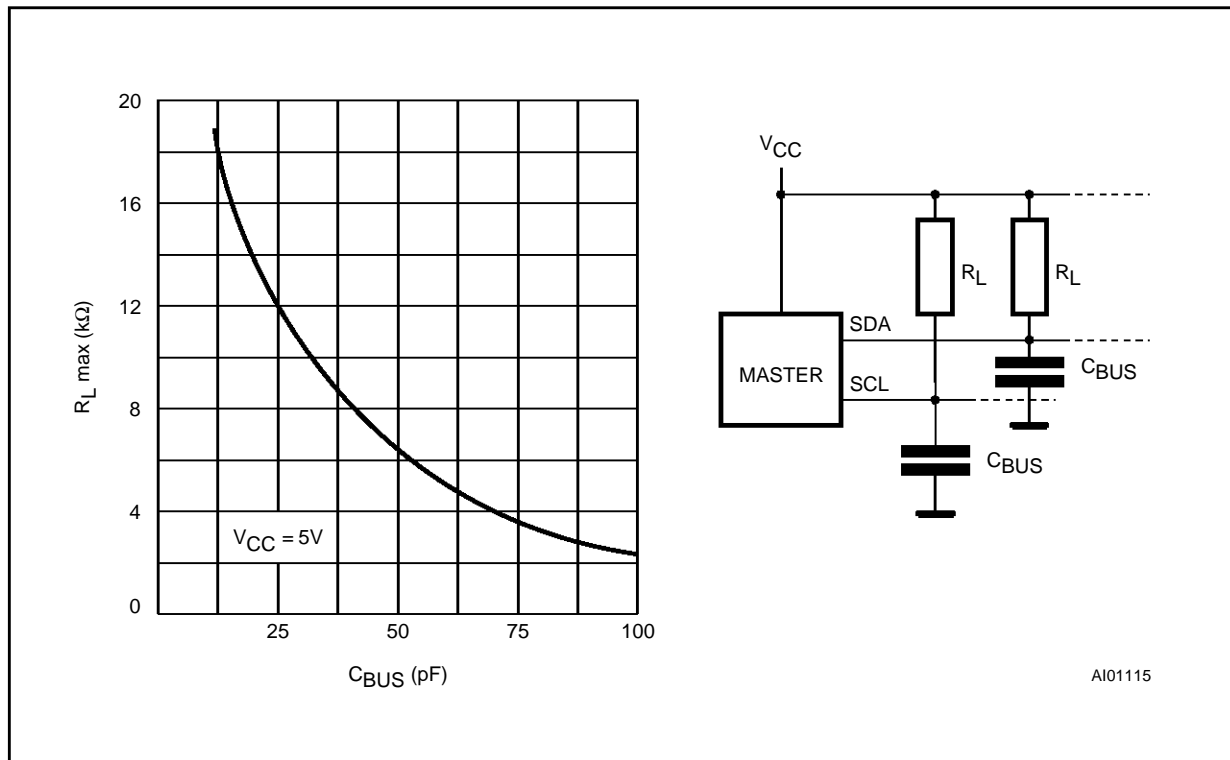
DEVICE OPERATION

I^2C Bus Background

The M24C64 supports the extended addressing I^2C protocol. This protocol defines any device that sends data onto the bus as a transmitter and any device that reads the data as a receiver. The device that controls the data transfer is known as the master and the other as the slave. The master will always initiate a data transfer and will provide the serial clock for synchronisation. The M24C64 is always slave devices in all communications.

Start Condition. START is identified by a high to low transition of the SDA line while the clock SCL is stable in the high state. A START condition must precede any command for data transfer. Except during a programming cycle, the M24C64 continuously monitors the SDA and SCL signals for a START condition and will not respond unless one is given.

Stop Condition. STOP is identified by a low to high transition of the SDA line while the clock SCL is stable in the high state. A STOP condition terminates communication between the M24C64 and the bus master. A STOP condition at the end of a Read command forces the standby state. A STOP condition at the end of a Write command triggers the internal EEPROM write cycle.

Acknowledge Bit (ACK). An acknowledge signal is used to indicate a successful data transfer. The bus transmitter, either master or slave, will release the SDA bus after sending 8 bits of data. During the 9th clock pulse the receiver pulls the SDA bus low to acknowledge the receipt of the 8 bits of data.

Data Input. During data input the M24C64 samples the SDA bus signal on the rising edge of the clock SCL. For correct device operation the SDA signal must be stable during the clock low to high transition and the data must change ONLY when the SCL line is low.

Device Selection. To start communication between the bus master and the slave M24C64, the master must initiate a START condition. The 8 bits sent after a START condition are made up of a device select of 4 bits that identifies the device type, 3 Chip Enable bits and one bit for a READ ($R\overline{W}$ = 1) or WRITE ($R\overline{W}$ = 0) operation. There are two modes both for read and write. These are summarised in Table 4 and described hereafter. A communication between the master and the slave is ended with a STOP condition.

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Table 5. Input Parameters [1] (T_A = 25 °C, f = 400 kHz)

Symbol	Parameter	Test Condition	Min	Max	Unit
C_{IN}	Input Capacitance (SDA)			8	pF
C_{IN}	Input Capacitance (other pins)			6	pF
Z_{WCL}	$\overline{WC}$ Input Impedance	$V_{IN} \leq 0.3\ V_{CC}$	5	20	kΩ
Z_{WCH}	$\overline{WC}$ Input Impedance	$V_{IN} \geq 0.7\ V_{CC}$	500		kΩ
t_{LP}	Low-pass filter input time constant (SDA and SCL)			100	ns

Note: 1. Sampled only, not 100% tested.

Table 6. DC Characteristics
(T_A = −40 to 85 °C or 0 to 70 °C; V_{CC} = 4.5V to 5.5V or 1.8V to 5.5V)

Symbol	Parameter	Test Condition	Min	Max	Unit
I_{LI}	Input Leakage Current (SCL, SDA, E0-E2)	$0V \leq V_{IN} \leq V_{CC}$		±2	µA
I_{LO}	Output Leakage Current	$0V \leq V_{OUT} \leq V_{CC}$ SDA in Hi-Z		±2	µA
I_{CC}	Supply Current (M24C64 series)	f_C = 400kHz (Rise/Fall time < 30ns)		2	mA
	Supply Current (M24C64-R series)			1	mA
I_{CC1}	Supply Current (Standby) (M24C64 series)	V_{IN} = V_{SS} or V_{CC}, V_{CC} = 5V		100	µA
		V_{IN} = V_{SS} or V_{CC}, V_{CC} = 5V, f_C = 400kHz		300	µA
I_{CC2}	Supply Current (Standby) (M24C64-R series)	V_{IN} = V_{SS} or V_{CC}, V_{CC} = 1.8V		5	µA
		V_{IN} = V_{SS} or V_{CC}, V_{CC} = 1.8V, f_C = 400kHz		50	µA
V_{IL}	Input Low Voltage (SCL, SDA)		−0.3	0.3 V_{CC}	V
V_{IH}	Input High Voltage (SCL, SDA)		0.7 V_{CC}	V_{CC} + 1	V
V_{IL}	Input Low Voltage (E0-E2, $\overline{WC}$)		−0.3	0.5	V
V_{IH}	Input High Voltage (E0-E2, $\overline{WC}$)		V_{CC} − 0.5	V_{CC} + 1	V
V_{OL}	Output Low Voltage	I_{OL} = 3mA, V_{CC} = 5V		0.4	V
	Output Low Voltage (M24C64-R series)	I_{OL} = 2.1mA, V_{CC} = 1.8V		0.4	V

Table 7. AC Characteristics
$(T_A = -40$ to $85\ °C$ or 0 to $70\ °C$; $V_{CC} = 4.5V$ to $5.5V$ or $1.8V$ to $5.5V)$

Symbol	Alt	Parameter	Min	Max	Unit
t_{CH1CH2}	t_R	Clock Rise Time		300	ns
t_{CL1CL2}	t_F	Clock Fall Time		300	ns
t_{DH1DH2} [(1)]	t_R	SDA Rise Time	20	300	ns
t_{DL1DL1} [(1)]	t_F	SDA Fall Time	20	300	ns
t_{CHDX} [(2)]	$t_{SU:STA}$	Clock High to Input Transition	600		ns
t_{CHCL}	t_{HIGH}	Clock Pulse Width High	600		ns
t_{DLCL}	$t_{HD:STA}$	Input Low to Clock Low (START)	600		ns
t_{CLDX}	$t_{HD:DAT}$	Clock Low to Input Transition	0		µs
t_{CLCH}	t_{LOW}	Clock Pulse Width Low	1.3		µs
t_{DXCX}	$t_{SU:DAT}$	Input Transition to Clock Transition	100		ns
t_{CHDH}	$t_{SU:STO}$	Clock High to Input High (STOP)	600		ns
t_{DHDL}	t_{BUF}	Input High to Input Low (Bus Free)	1.3		µs
t_{CLQV} [(3)]	t_{AA}	Clock Low to Next Data Out Valid	200	1000	ns
t_{CLQX}	t_{DH}	Data Out Hold Time	200		ns
f_C	f_{SCL}	Clock Frequency		400	kHz
t_W	t_{WR}	Write Time		10	ms

Notes: 1. Sampled only, not 100% tested.
2. For a reSTART condition, or following a write cycle.
3. The minimum value delays the falling/rising edge of SDA away from SCL = 1 in order to avoid unwanted START and/or STOP conditions.

AC MEASUREMENT CONDITIONS

Input Rise and Fall Times	$\leq$ 50ns
Input Pulse Voltages	$0.2V_{CC}$ to $0.8V_{CC}$
Input and Output Timing Ref. Voltages	$0.3V_{CC}$ to $0.7V_{CC}$

Figure 4. AC Testing Input Output Waveforms

DEVICE OPERATION (cont'd)

Memory Addressing. A data byte in the memory is addressed through 2 bytes of address information. The Most Significant Byte is sent first and the Least significant Byte is sent after. The Least Significant Byte addresses a block of 256 bytes, bits b12,b11,b10,b9,b8 of the Most Significant Byte select one block among 32 blocks (one block is 256 bytes).
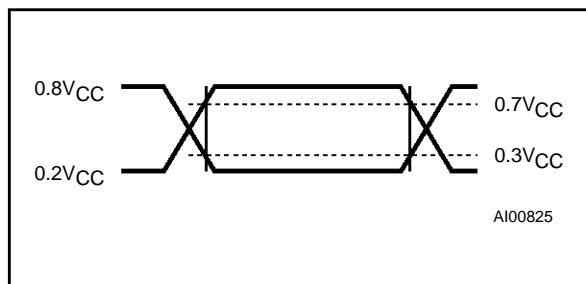
Most Significant Byte

X	X	X	b12	b11	b10	b9	b8

X = Don't Care.

Least Significant Byte

b7	b6	b5	b4	b3	b2	b1	b0

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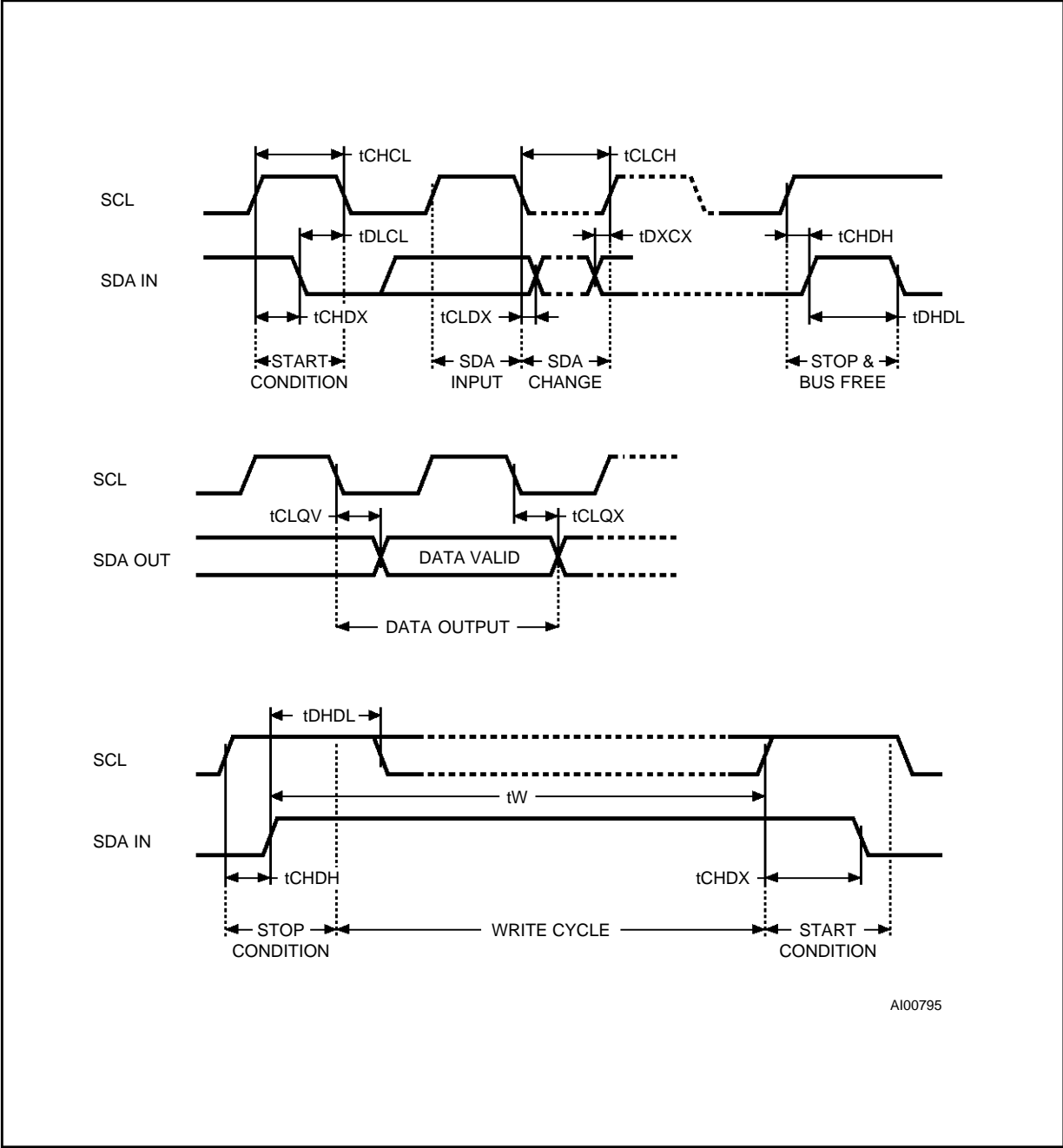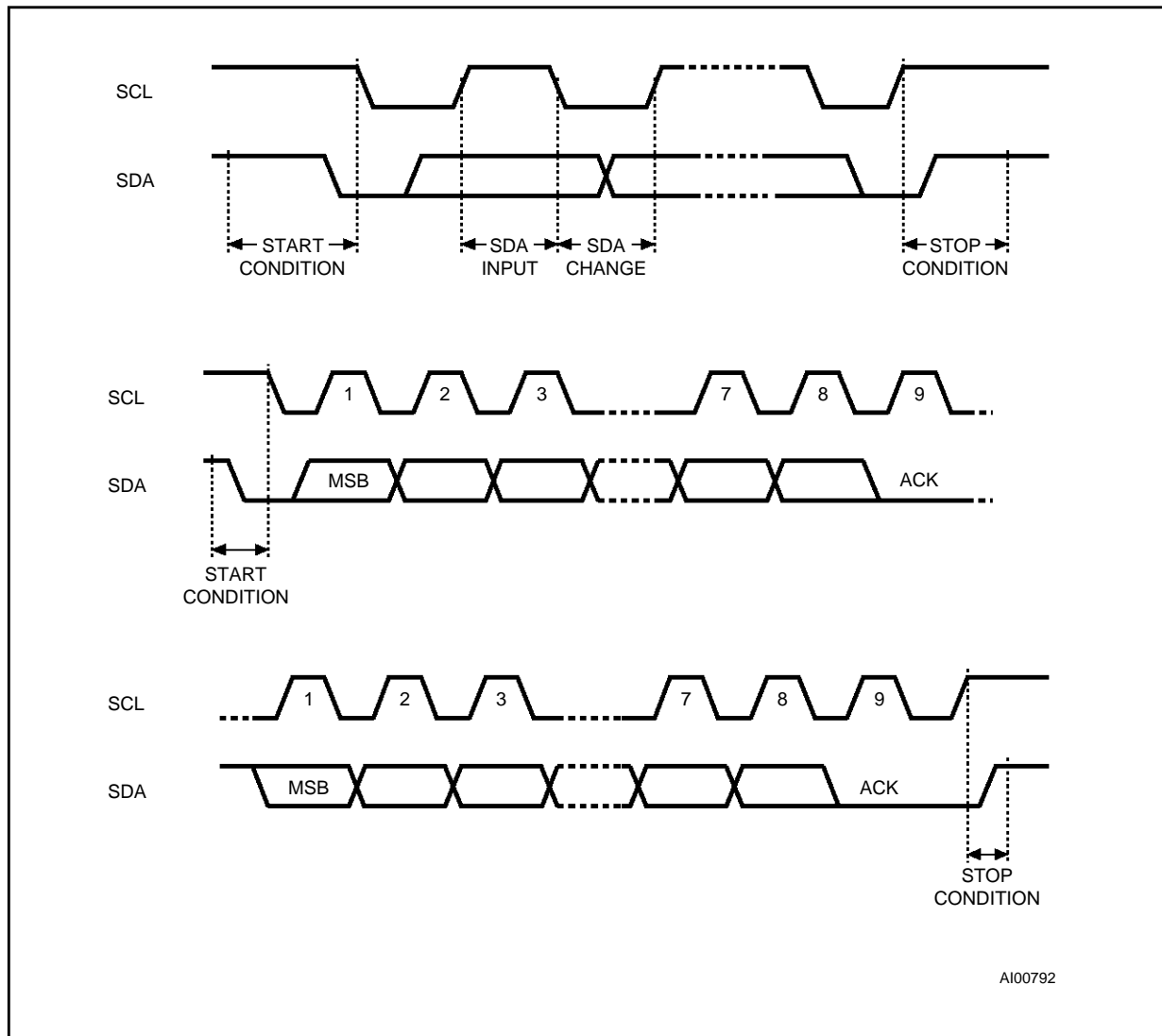**Figure 5. AC Waveforms**

AI00795

Figure 6. I²C Bus Protocol

AI00792

Write Operations

Following a START condition the master sends a device select code with the R$\overline{W}$ bit reset to '0'. The M24C64 acknowledges this and waits for 2 bytes of address. These 2 address bytes (8 bits each) provide access to any of the 32 blocks of 256 bytes each. Writing in the M24C64 may be inhibited if input pin $\overline{WC}$ is taken high.

For the M24C64 version, any write command with $\overline{WC}$ = '1' (during a period of time from the START condition untill the end of the 2 Bytes Address) will not modify data and will NOT be acknowledged on data bytes, as in Figure 9.

Byte Write. In the Byte Write mode the master sends one data byte, which is acknowledged by the

M24C64. The master then terminates the transfer by generating a STOP condition.

Page Write. The Page Write mode allows up to 32 bytes to be written in a single write cycle, provided that they are all located in the same row of 32 bytes in the memory, that is the same Address bits (b12 to b5). The master sends one up to 32 bytes of data, which are each acknowledged by the M24C64. After each byte is transfered, the internal byte address counter (5 Least Significant Bits only) is incremented. The transfer is terminated by the master generating a STOP condition. Care must be taken to avoid address counter 'roll-over' which could result in data being overwritten. Note that for any write mode, the generation by the master of the STOP condition starts the internal memory pro-

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gram cycle. This STOP condition will trigger an internal memory program cycle only if the STOP condition is internally decoded right after the ACK bit; any STOP condition decoded out of this "10th bit" time slot will not trigger the internal programming cycle. All inputs are disabled until the completion of this cycle and the M24C64 will not respond to any request.

Minimizing System Delay by Polling On ACK.
During the internal Write cycle, the M24C64 disables itself from the bus in order to copy the data from the internal latches to the memory cells. The maximum value of the Write time (t_W) is given in the AC Characteristics table, this timing value may be reduced by an ACK polling sequence issued by the master.

The sequence is:

– Initial condition: a Write is in progress (see Figure 7).

– Step 1: the Master issues a START condition followed by a Device Select byte. (1st byte of the new instruction)

– Step 2: if the M24C64 is internally writing, no ACK will be returned. The Master goes back to Step1. If the M24C64 has terminated the internal writing, it will issue an ACK. The M24C64 is ready to receive the second part of the instruction (the first byte of this instruction was already sent during Step1).
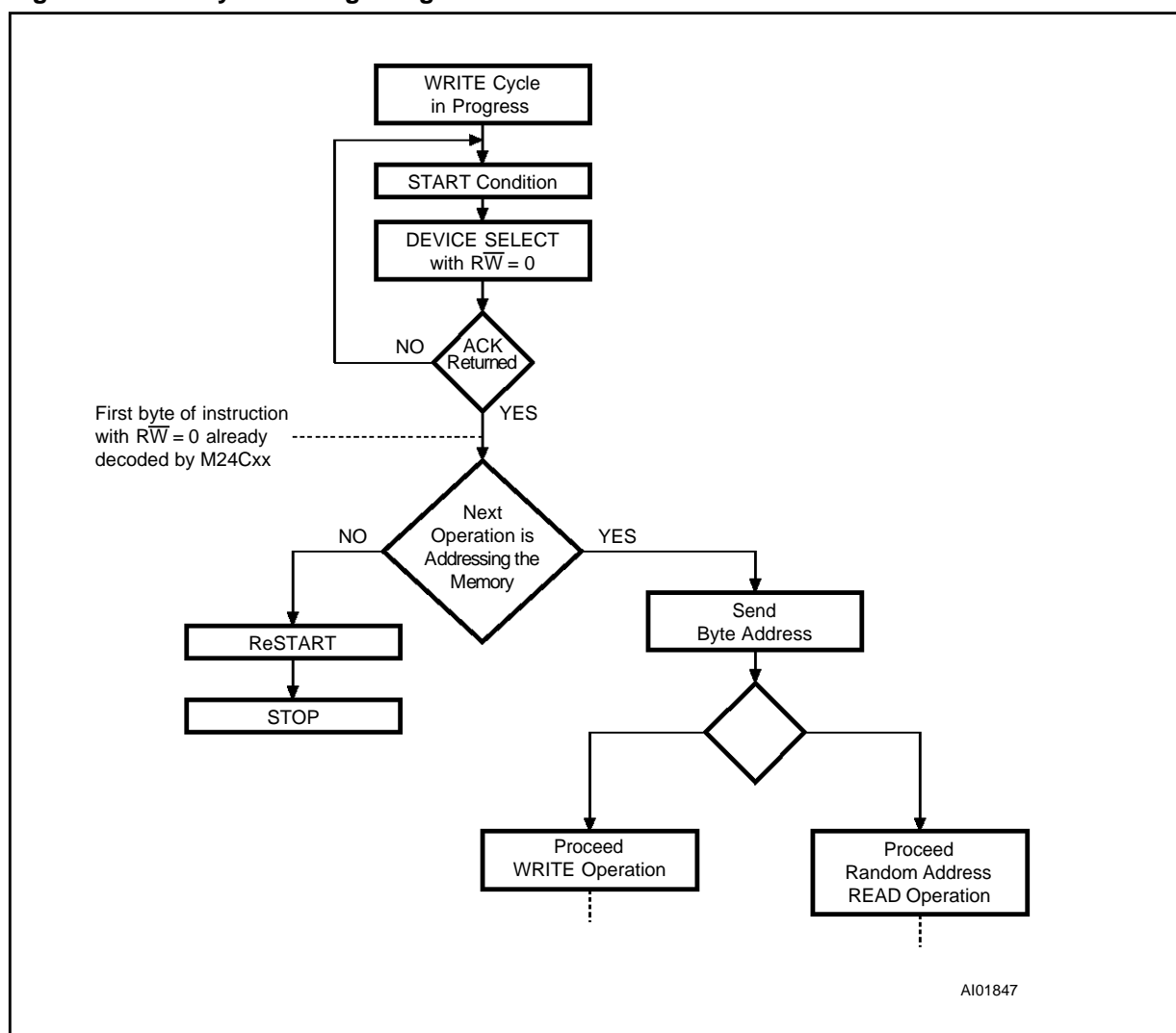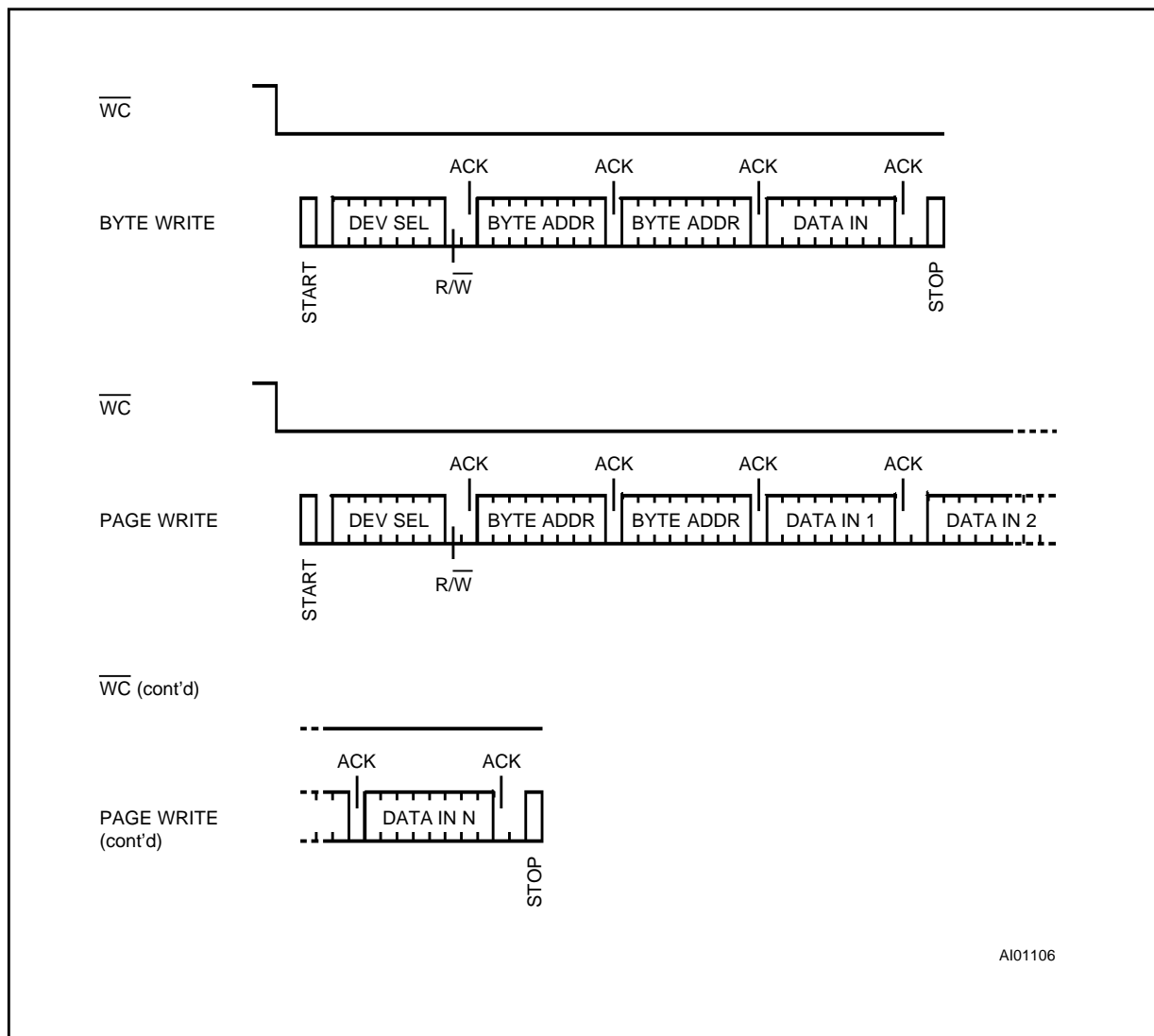
Figure 7. Write Cycle Polling using ACK

AI01847

Figure 8. Write Modes Sequence with Write Control = 0

AI01106

Read Operations

On delivery, the memory content is set at all "1's" (or FFh).

Current Address Read. The M24C64 has an internal 13 bits address counter. Each time a byte is read, this counter is incremented. For the Current Address Read mode, following a START condition, the master sends a Device Select with the R/$\overline{W}$ bit set to '1'. The M24C64 acknowledges this and outputs the byte addressed by the internal address counter. This counter is then incremented. The master does NOT acknowledge the byte output, but terminates the transfer with a STOP condition.

Random Address Read. A dummy write is performed to load the address into the address counter, see Figure 10. This is followed by another START condition from the master and the byte address repeated with the R/$\overline{W}$ bit set to '1'. The M24C64 acknowledges this and outputs the byte addressed. The master does NOT acknowledge the byte output, but terminates the transfer with a STOP condition.

Sequential Read. This mode can be initiated with either a Current Address Read or a Random Address Read. However, in this case the master DOES acknowledge the data byte output and the M24C64 continues to output the next byte in sequence. To terminate the stream of bytes, the master must NOT acknowledge the last byte out-

Figure 9. Write Modes Sequence with Write Control = 1

AI01120
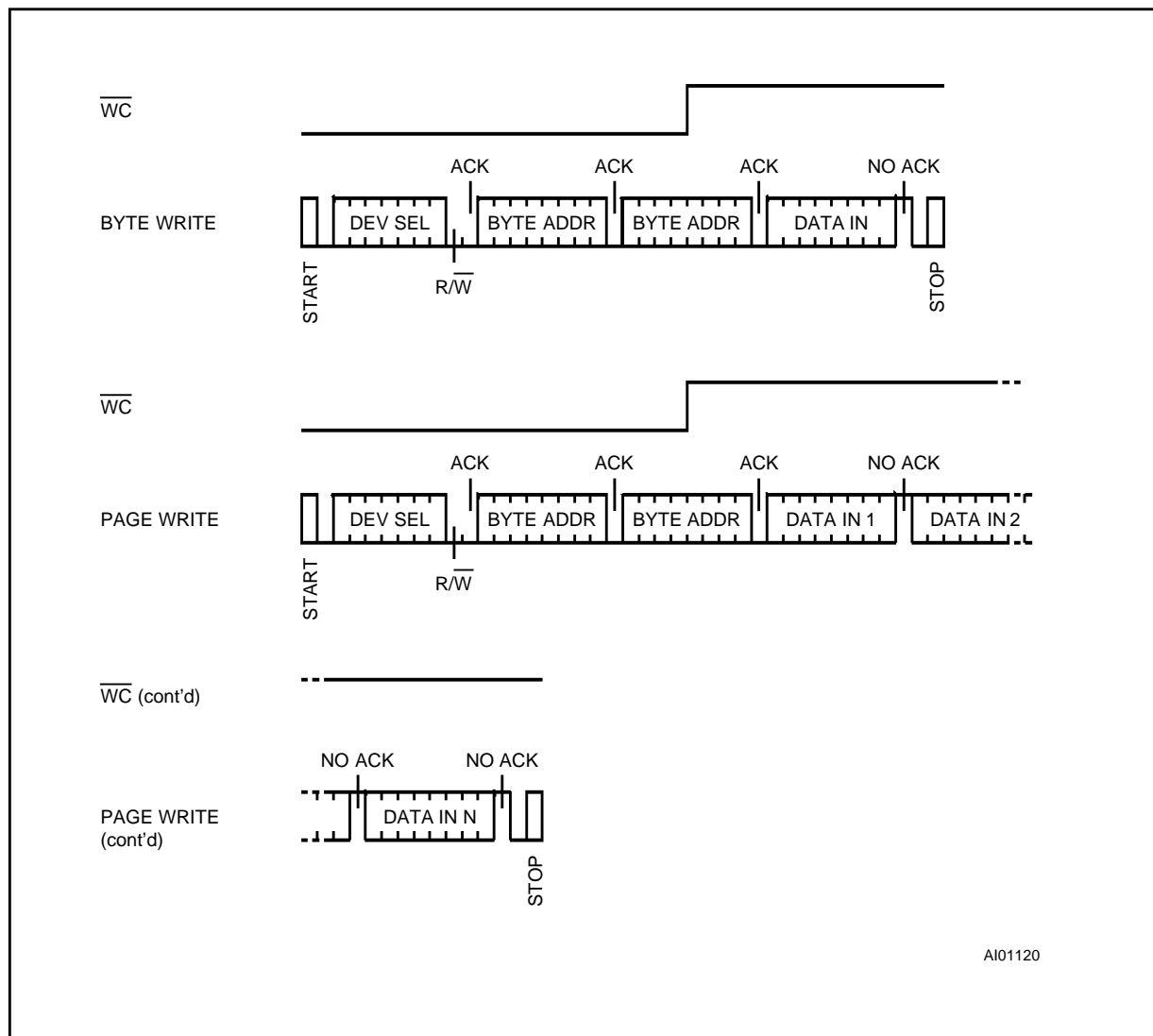
put, but MUST generate a STOP condition. The output data is from consecutive byte addresses, with the internal byte address counter automatically incremented after each byte output. After a count of the last memory address, the address counter will 'roll-over' and the memory will continue to output data.

Acknowledge in Read Mode. In all read modes the M24C64 waits for an acknowledge during the 9th bit time. If the master does not pull the SDA line low during this time, the M24C64 terminates the data transfer and switch to a standby state.
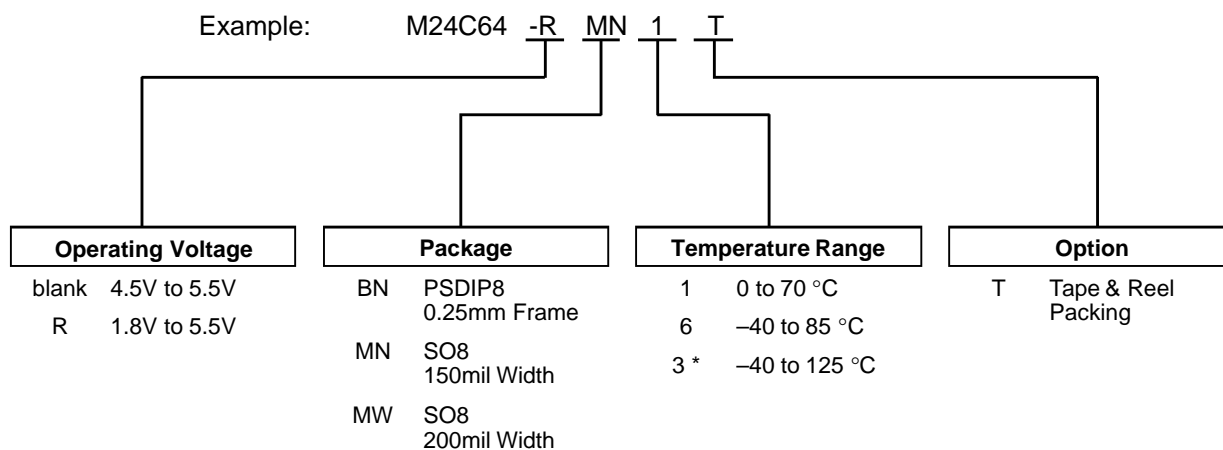
Figure 10. Read Modes Sequence
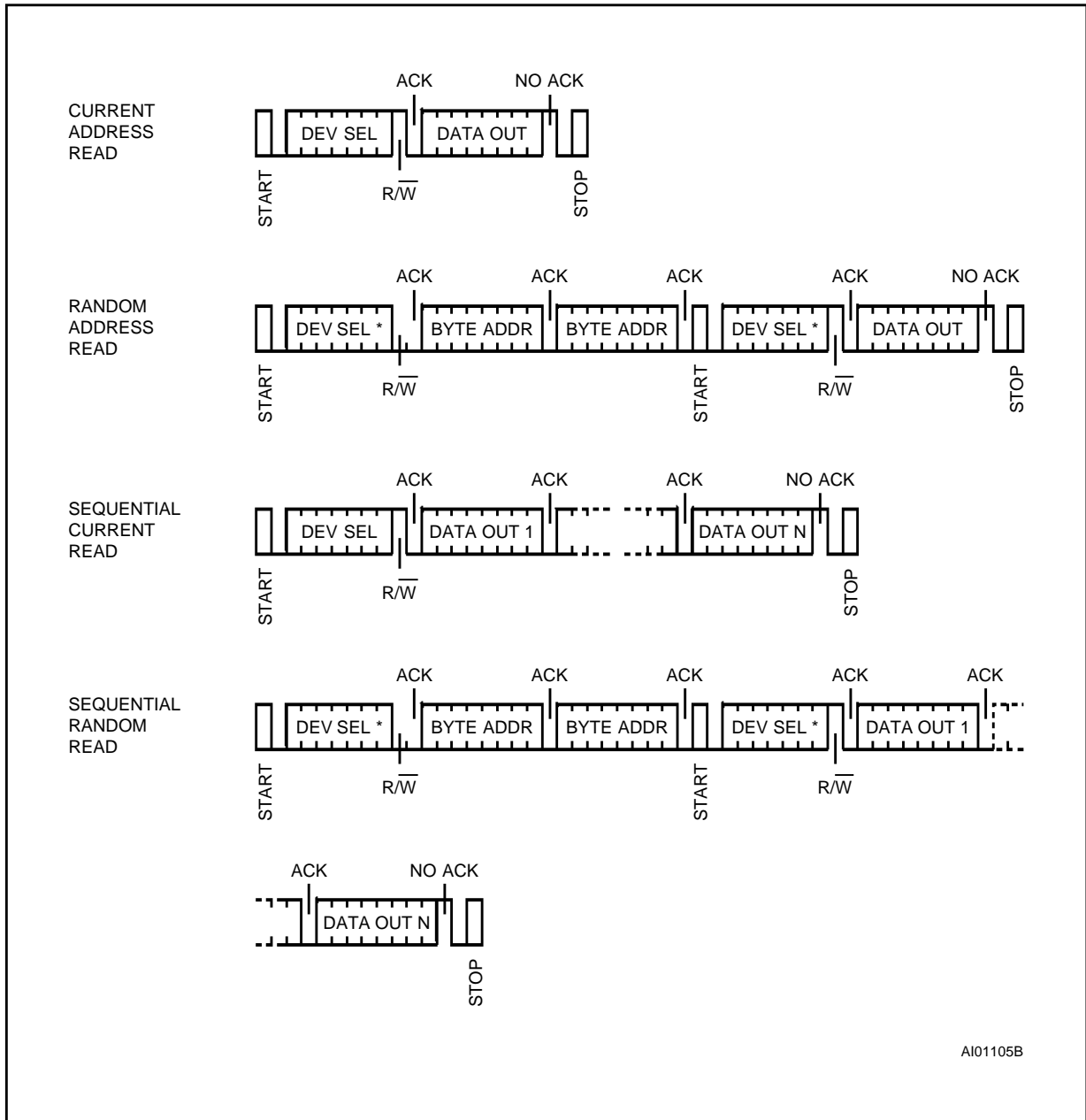
Note: * The 7 Most Significant bits of DEV SEL bytes of a Random Read (1st byte and 4th byte) must be identical.

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ORDERING INFORMATION SCHEME

Example: M24C64 -R MN 1 T

Operating Voltage		Package		Temperature Range		Option	
blank	4.5V to 5.5V	BN	PSDIP8 0.25mm Frame	1	0 to 70 °C	T	Tape & Reel Packing
R	1.8V to 5.5V	MN	SO8 150mil Width	6	−40 to 85 °C		
		MW	SO8 200mil Width	3 *	−40 to 125 °C		

Note: 3 * Temperature Range on special request only.

Parts are shipped with the memory content set at all "1's" (FFh).

For a list of available options (Operating Voltage, Range, Package, etc...) refer to the current Memory Shortform catalogue.

For further information on any aspect of this device, please contact the SGS-THOMSON Sales Office nearest to you.

PSDIP8 - 8 pin Plastic Skinny DIP, 0.25mm lead frame

Symb	mm			inches		
	Typ	Min	Max	Typ	Min	Max
A		3.90	5.90		0.154	0.232
A1		0.49	–		0.019	–
A2		3.30	5.30		0.130	0.209
B		0.36	0.56		0.014	0.022
B1		1.15	1.65		0.045	0.065
C		0.20	0.36		0.008	0.014
D		9.20	9.90		0.362	0.390
E	7.62	–	–	0.300	–	–
E1		6.00	6.70		0.236	0.264
e1	2.54	–	–	0.100	–	–
eA		7.80	–		0.307	–
eB			10.00			0.394
L		3.00	3.80		0.118	0.150
N	8			8		

PSDIP8

PSDIP-a

Drawing is not o scale

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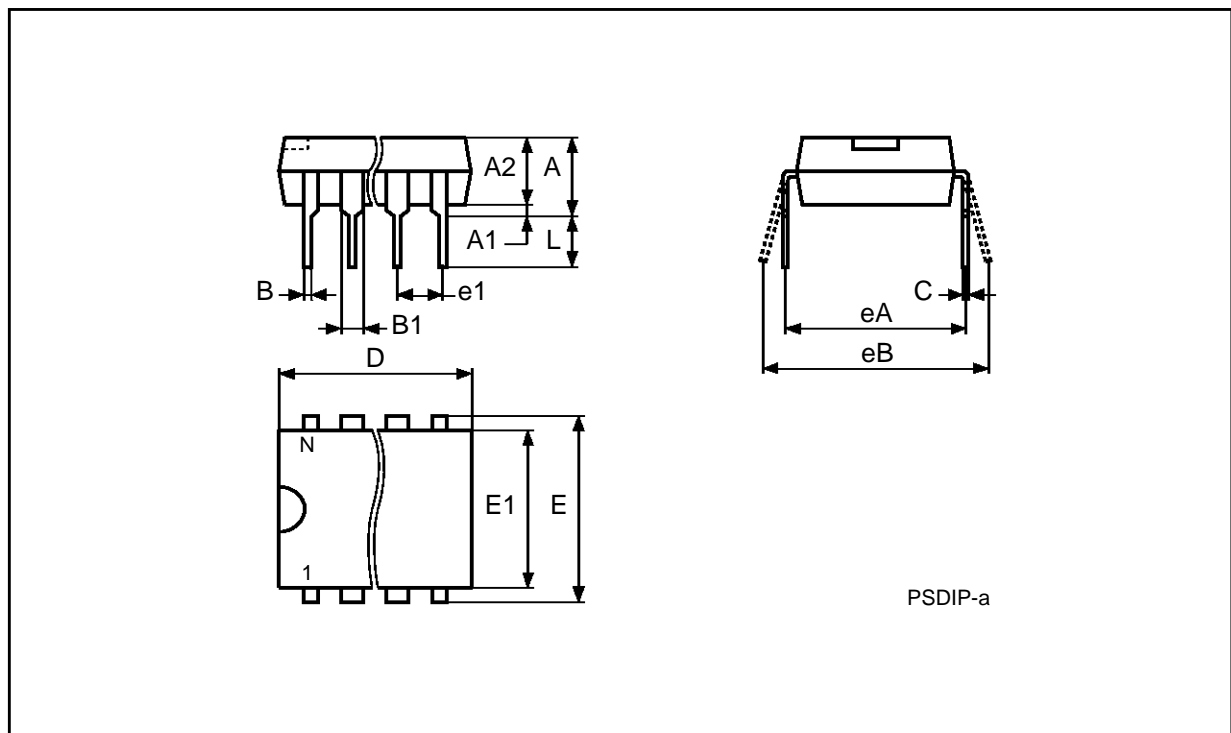
SO8 - 8 lead Plastic Small Outline, 150 mils body width

Symb	mm			inches		
	Typ	Min	Max	Typ	Min	Max
A		1.35	1.75		0.053	0.069
A1		0.10	0.25		0.004	0.010
B		0.33	0.51		0.013	0.020
C		0.19	0.25		0.007	0.010
D		4.80	5.00		0.189	0.197
E		3.80	4.00		0.150	0.157
e	1.27	–	–	0.050	–	–
H		5.80	6.20		0.228	0.244
h		0.25	0.50		0.010	0.020
L		0.40	0.90		0.016	0.035
α		0°	8°		0°	8°
N	8			8		
CP			0.10			0.004

SO8a

SO-a

Drawing is not to scale

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MICROELECTRONICS
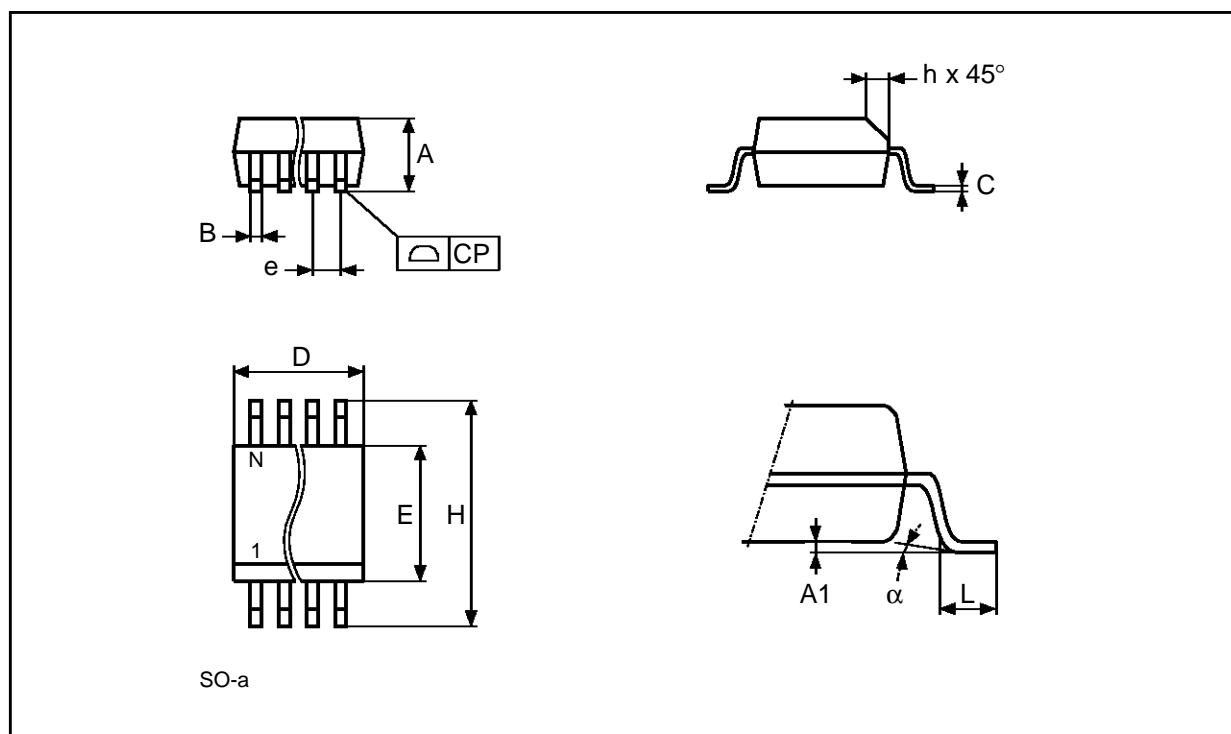
SO8 - 8 lead Plastic Small Outline, 200 mils body width

Symb	mm			inches		
	Typ	**Min**	**Max**	**Typ**	**Min**	**Max**
A			2.03			0.080
A1		0.10	0.25		0.004	0.010
A2			1.78			0.070
B		0.35	0.45		0.014	0.018
C	0.20	–	–	0.008	–	–
D		5.15	5.35		0.203	0.211
E		5.20	5.40		0.205	0.213
e	1.27	–	–	0.050	–	–
H		7.70	8.10		0.303	0.319
L		0.50	0.80		0.020	0.031
α		0°	10°		0°	10°
N		8			8	
CP			0.10			0.004

SO8b

SO-b

Drawing is not to scale

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